

1. General description

Planar passivated high commutation three quadrant triac in a SOT428 (DPAK) surface mountable plastic package. This "series D" triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers and logic ICs including microcontrollers.

2. Features and benefits

- 3Q technology for improved noise immunity
- · Direct gate triggering from low power drivers and logic ICs
- High commutation capability
- High voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Surface mountable package
- Triggering in three quadrants only
- Very sensitve gate for easy logic level triggering

3. Applications

- Electronic thermostats
- · General purpose motor controls

4. Quick reference data

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| Table 1. Quick | reference data | | | | | |
|---------------------|------------------------------------------|--------------------------------------------------------------------------------------------------------|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 102 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | - | 8 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u> | - | - | 65 | A |
| | | full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms | - | - | 72 | A |
| Tj | junction temperature | | - | - | 125 | °C |
| Static charac | teristics | | | | | , |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | - | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | - | 5 | mA |

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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------|-----|-----|------|------|
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | - | 5 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 15 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u> | - | - | 1.65 | V |
| Dynamic ch | haracteristics | · | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 110 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 20 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 8 A; dV _{com} /dt = 0.1 V/µs; gate open circuit | 6 | - | - | A/ms |
| | | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 8 A; dV _{com} /dt = 10 V/µs; gate open circuit; Fig. 12 | 2 | - | - | A/ms |

5. Pinning information

| Table 2. F | Pinning inf | formation | | |
|------------|-------------|-----------------------------------|--------------------|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | [<u> </u> | T2-T1 |
| 2 | T2 | main terminal 2 | | sym051 |
| 3 | G | gate | | Symust |
| mb | Τ2 | mounting base; main terminal 2 | DPAK (SOT428) | |

6. Ordering information

| Table 3. Ordering infor | mation | | | | | |
|-------------------------|---------|---------------------------------------------------------------------------------|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BTA208S-600D | DPAK | plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped) | SOT428 | | | |

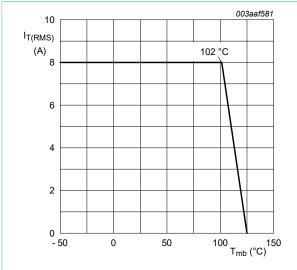


7. Limiting values

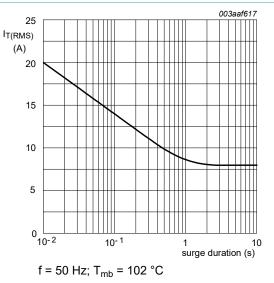
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|------------------------------------------|-----------------------------------------------------------------------------------|-----|-----|------|
| V _{DRM} | repetitive peak off-state voltage | | - | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; T _{mb} ≤ 102 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u> | - | 8 | A |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5 | - | 65 | A |
| | | full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms | - | 72 | А |
| l ² t | I ² t for fusing | t _p = 10 ms; SIN | - | 21 | A²s |
| dl _T /dt | rate of rise of on-state current | I _G = 10 mA | - | 100 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| T _i | junction temperature | | - | 125 | °C |

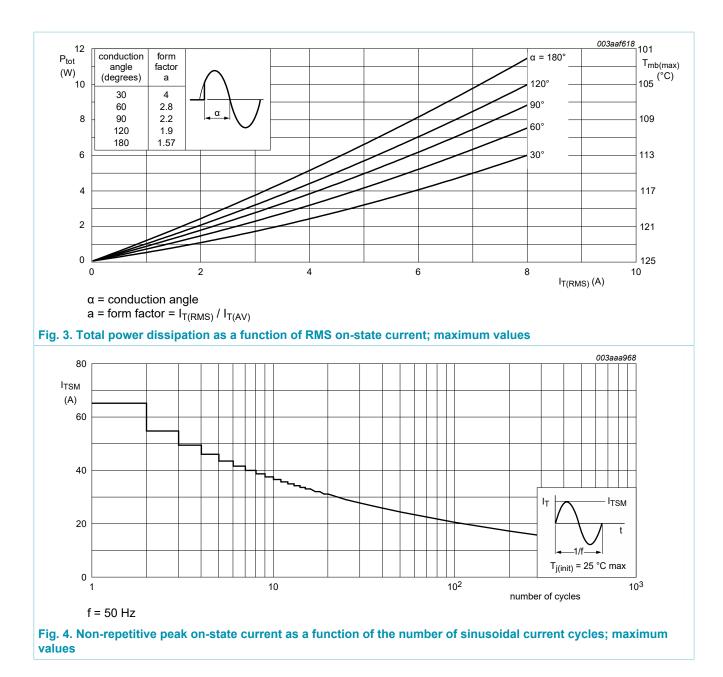






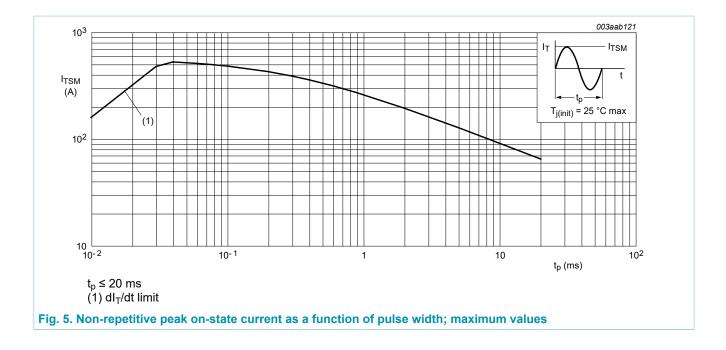


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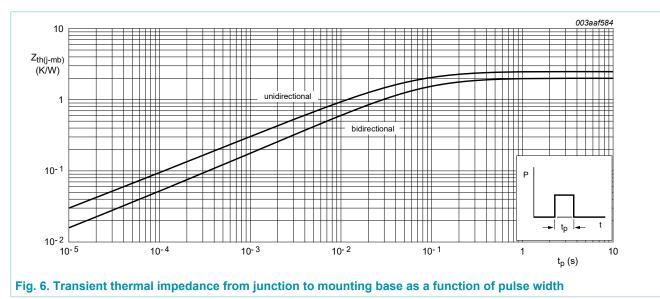
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8. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|------------------------------------------------------------|-------------------------------------|-----|-----|-----|------|
| 1 (110) | thermal resistance | full cycle; <u>Fig. 6</u> | - | - | 2 | K/W |
| | from junction to mounting base | half cycle; <u>Fig. 6</u> | - | - | 2.4 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient free air | printed circuit board (FR4) mounted | - | 75 | - | K/W |



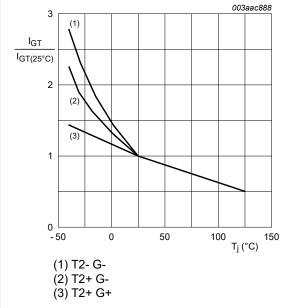
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9. Characteristics

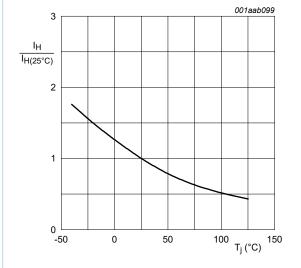
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|-----|------|------|
| Static chara | acteristics | · · · | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | - | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | - | 5 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | - | 5 | mA |
| ΙL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | - | 15 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 25 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | - | 25 | mA |
| I _Н | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 15 | mA |
| V _T | on-state voltage | I _T = 10 A; T _j = 25 °C; <u>Fig. 10</u> | - | - | 1.65 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | - | 0.5 | mA |
| Dynamic ch | naracteristics | · · · | | 1 | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T _j = 110 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 20 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 8 A; dV _{com} /dt = 0.1 V/µs; gate open circuit | 6 | - | - | A/ms |
| | | $V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 8 \text{ A};$ $dV_{com}/dt = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit};$ Fig. 12 | 2 | - | - | A/ms |

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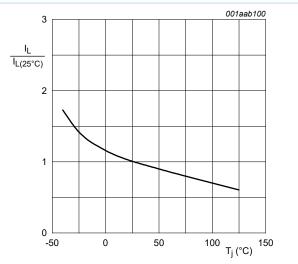
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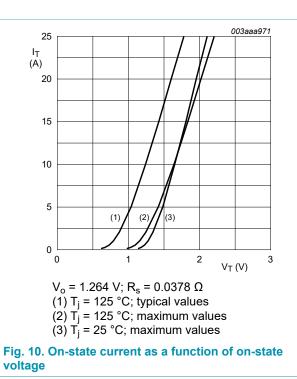






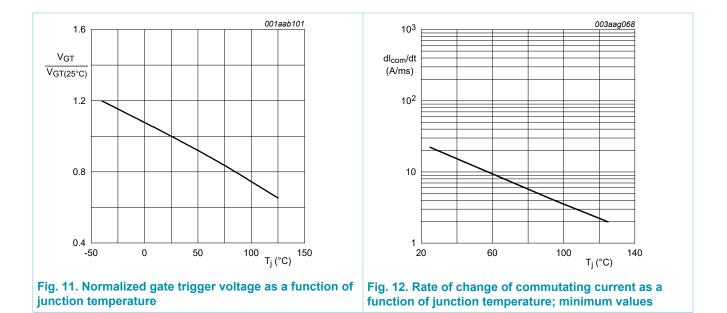






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10. Package outline

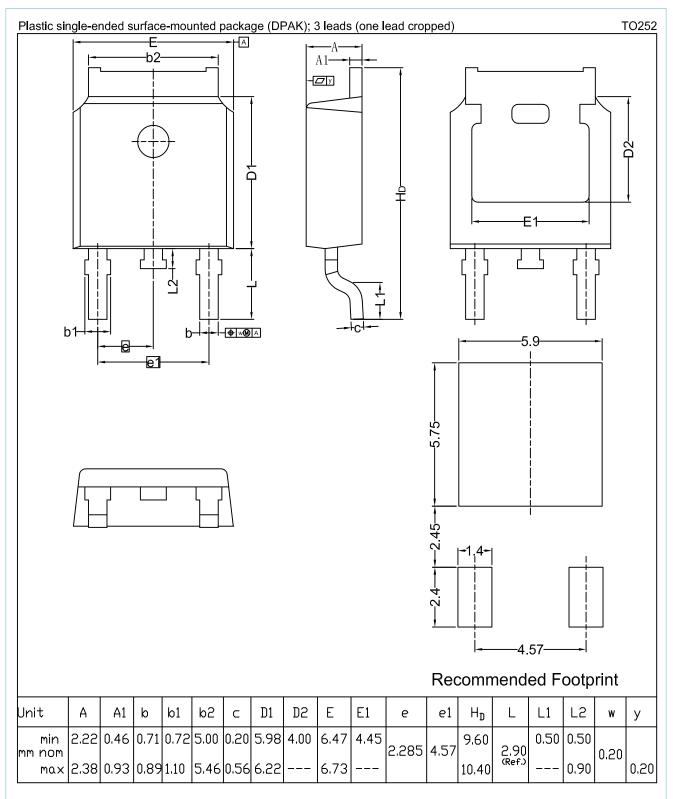


Fig. 13. Package outline DPAK (SOT428)

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| Document status [1][2] | Product status [<u>3]</u> | Definition |
|--------------------------------------|-------------------------------|---------------------------------------------------------------------------------------------|
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